

DOCKET NO: 251265US2RD DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
MASAYUKI ISHIKAWA ET AL :
SERIAL NO: NEW DIVISIONAL :
APPLICATION :
FILED: HEREWITH :
FOR: SEMICONDUCTOR DEVICE, :
SEMICONDUCTOR LASER, THEIR :
MANUFACTURING METHODS AD :
ETCHING METHODS

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified divisional application as follows:

Amendment to the Specification begins on page 2.

Amendments to the Claims begin on page 3 of this paper.

Remarks/Arguments begin on page 6 of this paper.